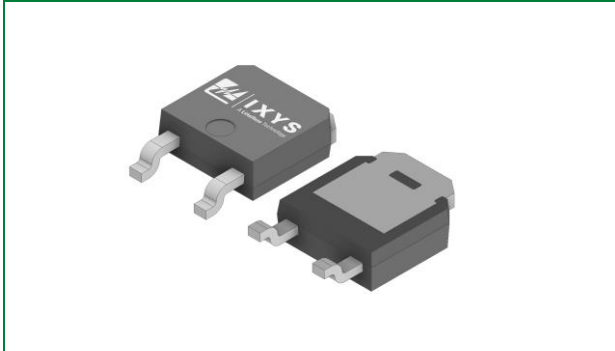


LSIC2SD065C10A 650 V, 10 A SiC Schottky Barrier Diode

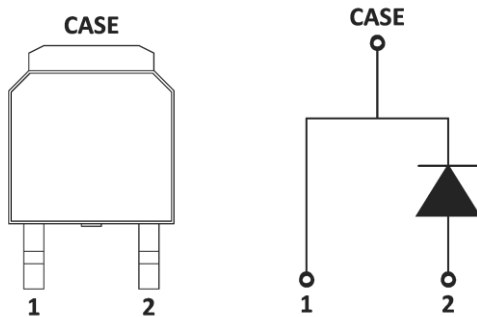


Agency Approvals and Environmental

Environmental Approvals



Circuit Diagram TO-252-2L



Product Summary

Characteristic	Value	Unit
V_{RRM}	650	V
$I_F (T_C \leq 135^\circ\text{C})$	13	A
$Q_C (V_R: 0 - 400\text{ V})$	31	nC

Features

- AEC-Q101 qualified
- MSL 1 Rated
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes
- RoHS compliant, lead-free, and halogen-free

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters
- Uninterruptable power supplies
- Industrial motor drives
- Battery chargers
- High speed rectifier

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1. Maximum Ratings

Characteristic	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	650	V
DC Blocking Voltage	V_R	-	650	V
Continuous Forward Current	I_F	$T_C = 25\text{ }^{\circ}\text{C}$	28	A
		$T_C = 135\text{ }^{\circ}\text{C}$	13	
		$T_C = 148\text{ }^{\circ}\text{C}$	10	
Non-repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ }^{\circ}\text{C}$, $t_p = 10\text{ ms}$, Half sine pulse	48	A
I^2t	$\int I^2 dt$	$T_C = 25\text{ }^{\circ}\text{C}$, $t_p = 10\text{ ms}$, Half sine pulse	11.5	A ² s
Power Dissipation	P_{Tot}	$T_C = 25\text{ }^{\circ}\text{C}$	100	W
		$T_C = 110\text{ }^{\circ}\text{C}$	43	
Operating Junction Temperature	T_J	-	-55 to 175	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-	-55 to 150	$^{\circ}\text{C}$
Lead Temperature for Soldering (MSL 1 Rated)	T_{SOLD}	-	260	$^{\circ}\text{C}$

2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance	$R_{th,JC, max}$	1.5	$^{\circ}\text{C/W}$

3. Electrical Characteristics

Characteristic	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Forward Voltage	V_F	$I_F = 10\text{ A}$, $T_J = 25\text{ }^{\circ}\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}$, $T_J = 175\text{ }^{\circ}\text{C}$	-	1.8	-	
Reverse Current	I_R	$V_R = 650\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	-	<1	100	μA
		$V_R = 650\text{ V}$, $T_J = 175\text{ }^{\circ}\text{C}$	-	20	-	
Total Capacitance	C	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$	-	470	-	pF
		$V_R = 200\text{ V}$, $f = 1\text{ MHz}$	-	60	-	
		$V_R = 400\text{ V}$, $f = 1\text{ MHz}$	-	43	-	
Total Capacitive Charge	Q_C	$V_R = 400\text{ V}$, $Q_C = \int C(V) dV$	-	31	-	nC
Capacitance Stored Energy	E_C	$V_R = 400\text{ V}$	-	3.4		μJ

4. Performance Curves

Figure 1. Typical Forward Characteristics

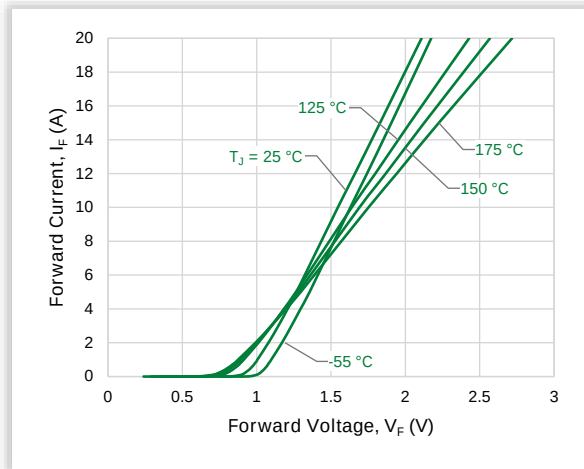


Figure 2. Typical Reverse Characteristics

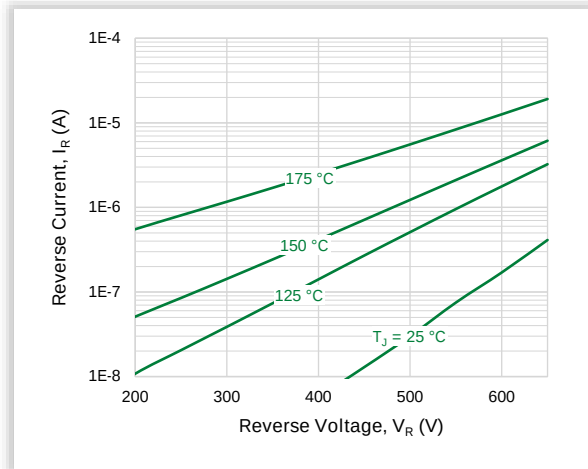


Figure 3. Power Derating

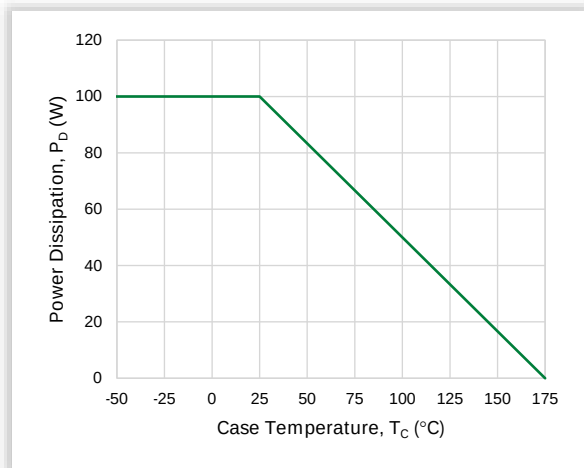


Figure 4. Current Derating

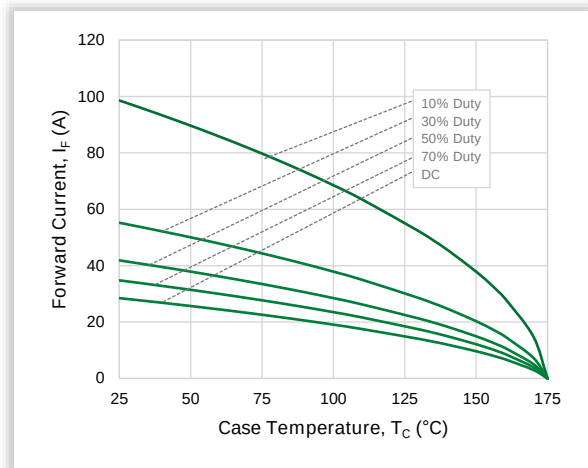


Figure 5. Capacitance vs. Reverse Voltage

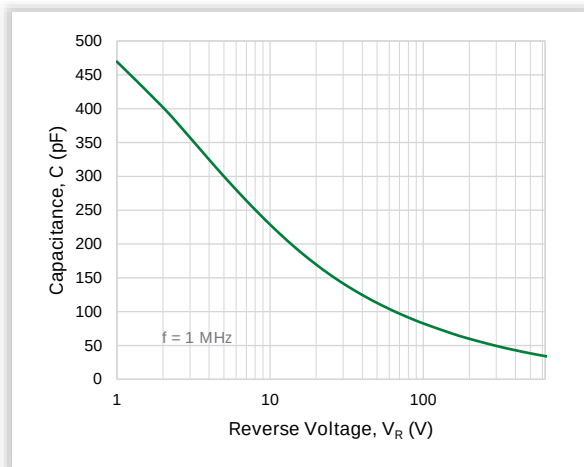


Figure 6. Capacitive Charge vs. Reverse Voltage

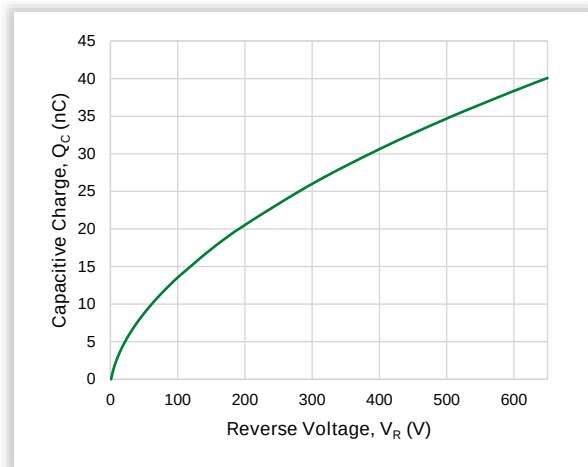


Figure 7. Stored Energy vs. Reverse Voltage

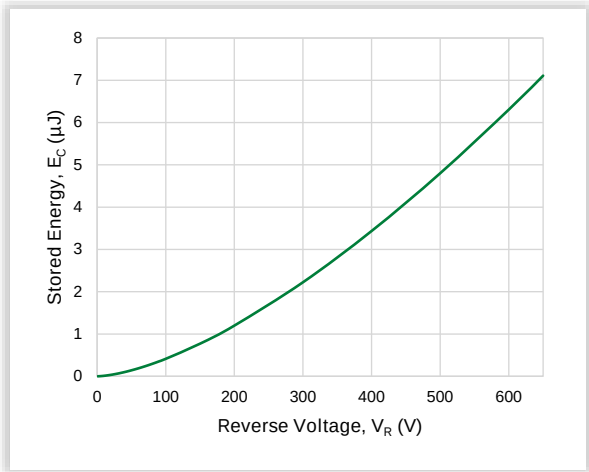
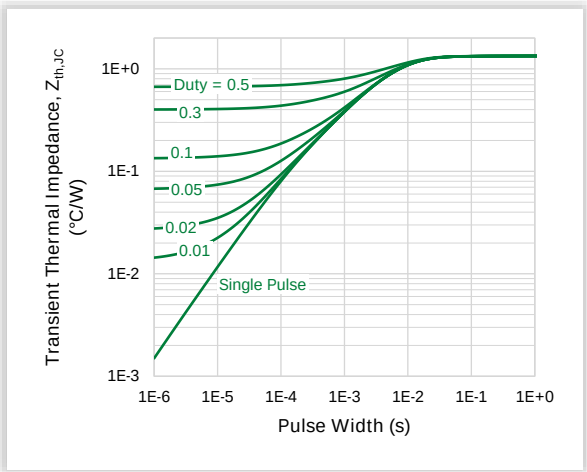
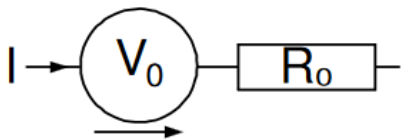


Figure 8. Transient Thermal Impedance



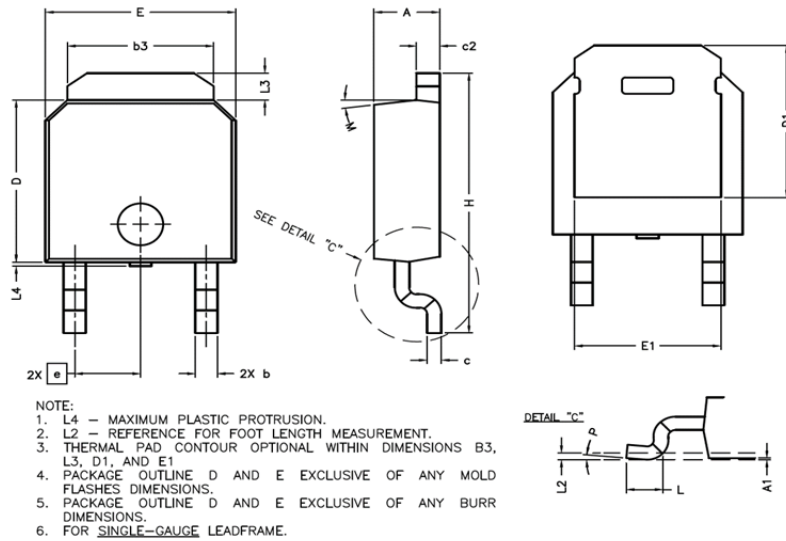
5. V_F Model for Simulations



$$V_F(T_J) = V_0 + IR_0$$
$$V_0 = -1.14 \times 10^{-3} \cdot T_J + 1.01 \times 10^0$$
$$R_0 = 8.08 \times 10^{-7} \cdot T_J^2 + 9.46 \times 10^{-5} \cdot T_J + 5.34 \times 10^{-2}$$

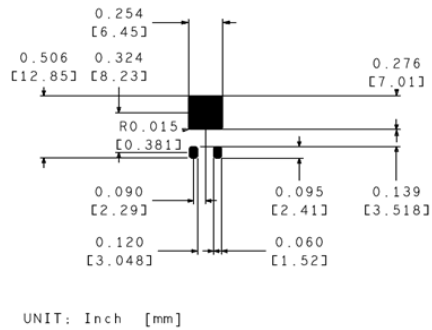
- Notes:
- T_J is junction temperature in $^{\circ}C$
 - Range valid from $25^{\circ}C$ to $175^{\circ}C$
 - Model represents performance of a typical part

6. Package Dimensions

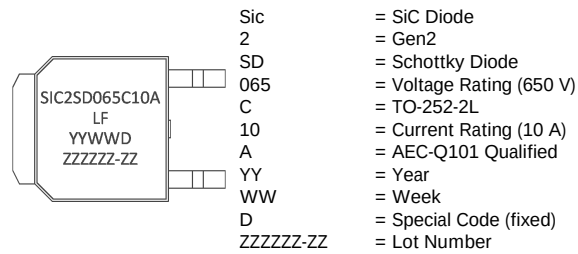


Symbol	Millimeters	
	Min	Max
A	2.159	2.413
A1	-	0.127
b	0.635	1.067
b3	4.953	5.461
c	0.457	0.610
c2	-	0.889
(c2)	0.457	0.610
D	5.969	6.223
D1	5.207	5.715
E	6.350	6.731
E1	4.318	5.207
e	2.29 REF.	
H	9.398	10.414
L	1.016	1.778
L2	0.25 REF.	
L3	0.889	1.270
L4	0.000	0.152
M	15°	
P	-	5°

Recommended Solder Pad Layout



7. Part Numbering and Marking

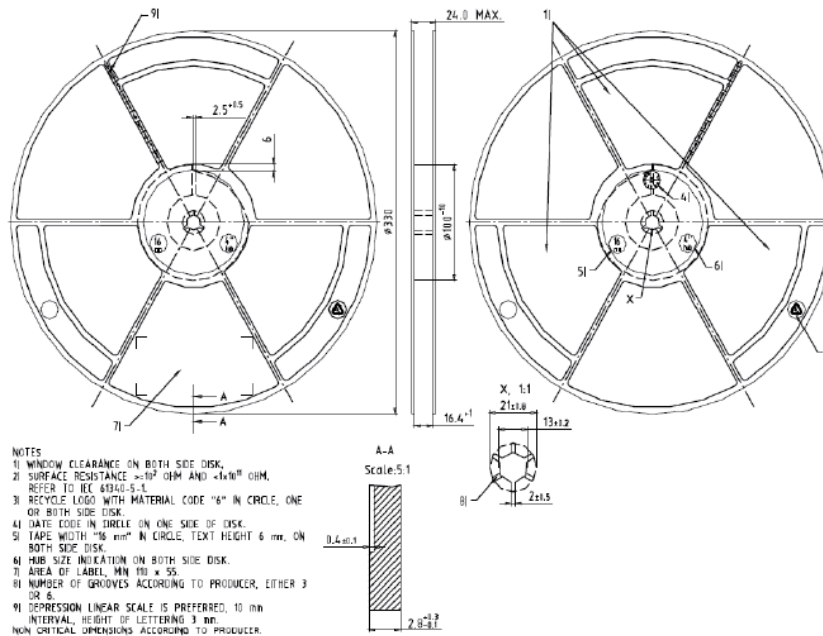
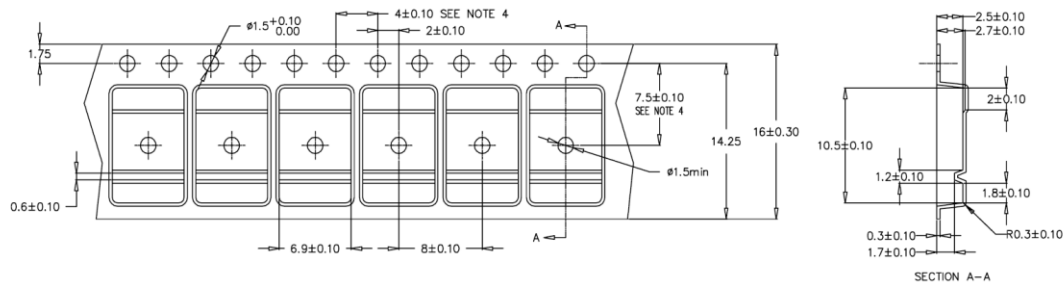


8. Packing Options

Part Number	Marking	Packing Mode	M.O.Q.
LSIC2SD065C10A	SIC2SD065C10A	Tape and Reel	2500

9. Packing Specifications

Carrier Tape and Reel Specification TO-252-2L



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